

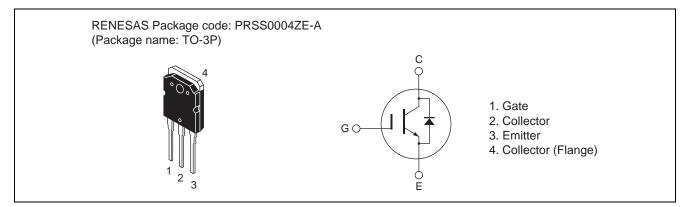
RJH60F0DPK

Silicon N Channel IGBT High Speed Power Switching R07DS0234EJ0200 (Previous: REJ03G1834-0100) Rev.2.00 Dec 14, 2010

Features

- Low collector to emitter saturation voltage $V_{CE(sat)} = 1.4$ V typ. (at $I_C = 25$ A, $V_{GE} = 15$ V, $Ta = 25^{\circ}C$)
- Built in fast recovery diode in one package
- Trench gate and thin wafer technology
- High speed switching $t_f = 90$ ns typ. (at $I_C = 30$ A, $V_{CC} = 400$ V, $V_{GE} = 15$ V, $Rg = 5 \Omega$, $Ta = 25^{\circ}C$, inductive load)

Outline



Absolute Maximum Ratings

 $(Tc = 25^{\circ}C)$ Unit Item Symbol Ratings Collector to emitter voltage 600 V V_{CES} V Gate to emitter voltage $\mathsf{V}_{\mathsf{GES}}$ ±30 I_C Note1 Tc = 25 °C 50 А Collector current Ic Note1 $Tc = 100^{\circ}C$ 25 А ic(peak) Note1 Collector peak current 100 А iDF(peak) Note2 А Collector to emitter diode forward peak current 100 Collector dissipation 201.6 W P_{C} Junction to case thermal impedance θj-c 0.62 °C/W Channel temperature 150 °С Τj -55 to +150 °C Storage temperature Tstg

Notes: 1. Pulse width limited by safe operating area.

2. PW \leq 5 μ s, duty cycle \leq 1%



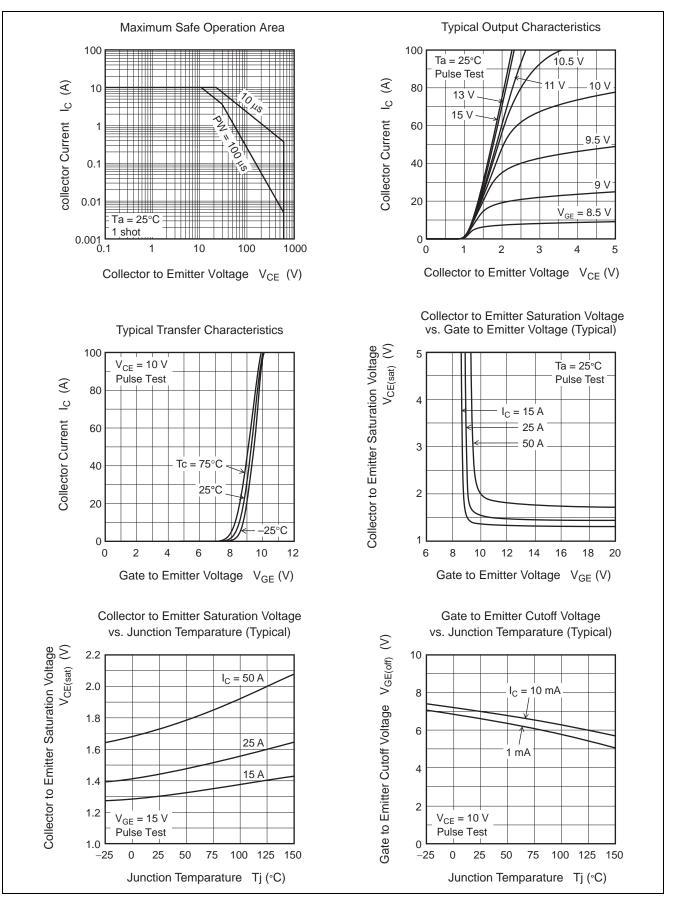
Electrical Characteristics

						$(Tj = 25^{\circ}C)$
Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Zero gate voltage collector current	I _{CES}	_	—	100	μΑ	$V_{CE} = 600V, V_{GE} = 0$
Gate to emitter leak current	I _{GES}	_	_	±1	μΑ	$V_{GE} = \pm 30 \text{ V}, V_{CE} = 0$
Gate to emitter cutoff voltage	V _{GE(off)}	4	—	8	V	$V_{CE} = 10V, I_{C} = 1 \text{ mA}$
Collector to emitter saturation voltage	V _{CE(sat)}	_	1.4	1.82	V	$I_{C} = 25 \text{ A}, V_{GE} = 15 V^{Note3}$
		_	1.7	_	V	$I_{C} = 50 \text{ A}, V_{GE} = 15 V^{Note3}$
Input capacitance	Cies	_	1550		pF	V _{CE} = 25 V
Output capacitance	Coes	_	82		pF	$V_{GE} = 0 V$
Reverse transfer capacitance	Cres	_	26		pF	f = 1 MHz
Switching time	t _{d(on)}	_	46		ns	I _C = 30 A,
	tr	_	92		ns	$V_{CE} = 400 \text{ V}, V_{GE} = 15 \text{ V}$
	t _{d(off)}		70		ns	$Rg = 5 \Omega^{Note3}$
	t _f		90		ns	Inductive load
C-E diode forward voltage	V _{ECF1}		1.6	2.1	V	$I_F = 20 \text{ A}^{\text{Note3}}$
C-E diode forward voltage	V _{ECF2}		1.9		V	$I_F = 40 \text{ A}^{\text{Note3}}$
C-E diode reverse recovery time	t _{rr}		140		ns	I _F = 20 A
						di _F /dt = 100 A/µs

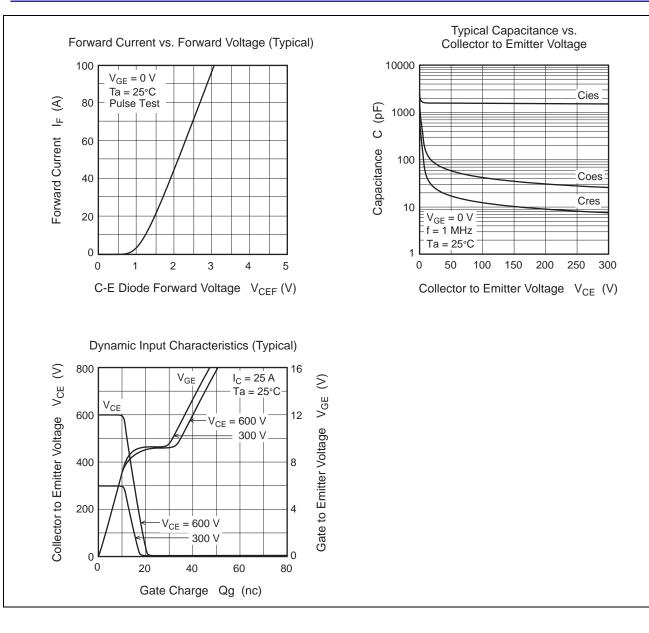
Notes: 3. Pulse test



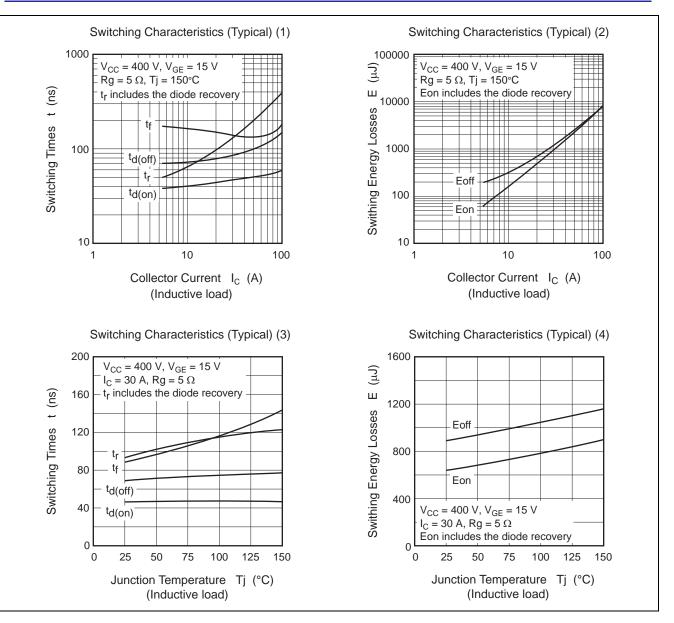
Main Characteristics



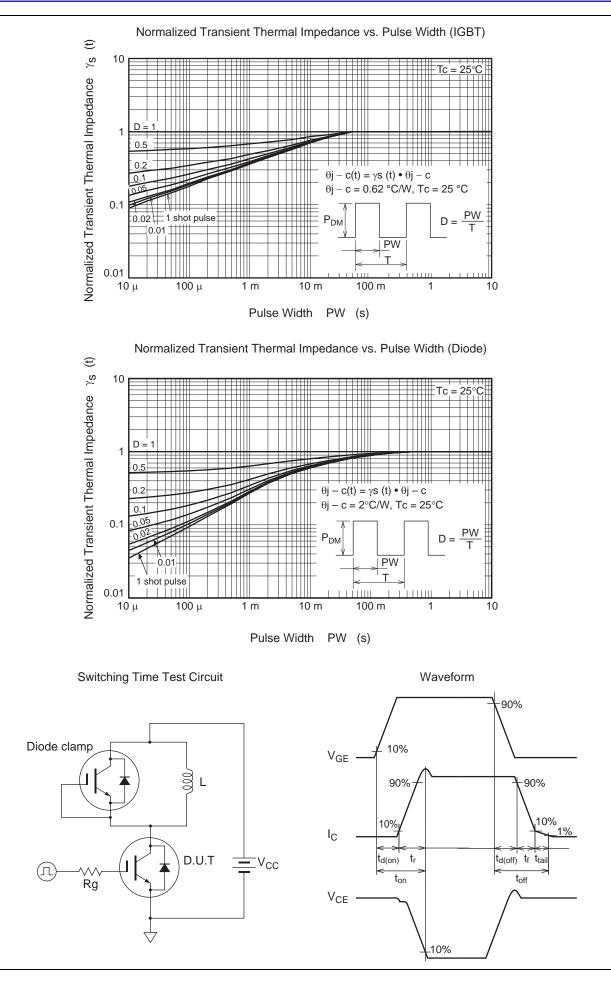






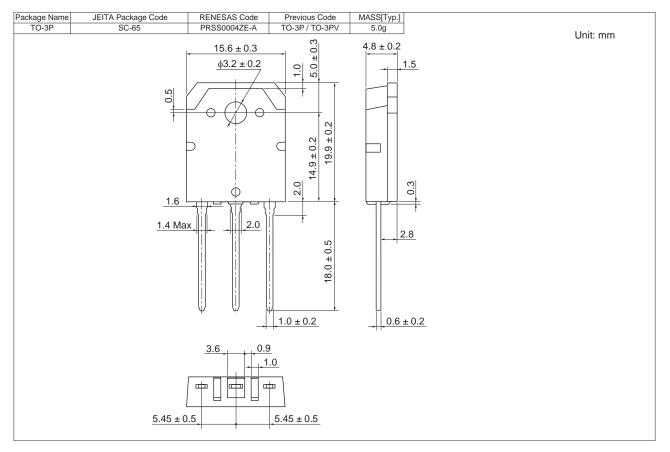








Package Dimensions



Ordering Information

Orderable Part Number	Quantity	Shipping Container	
RJH60F0DPK-00-T0	360 pcs	Box (Tube)	



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